

**M51995P,FP****SWITCHING REGULATOR CONTROL****DESCRIPTION**

M51995 is the primary switching regulator controller which is especially designed to get the regulated DC voltage from AC power supply.

This IC can directly drive the MOS-FET with fast rise and fast fall output pulse.

Type M51995 has the functions of not only high frequency OSC and fast output drive but also current limit with fast response and high sensibility so the true "fast switching regulator" can be realized.

It has another big feature of current protection to short and over current, owing to the integrated timer-type protection circuit, if few parts are added to the primary side.

The M51995 is equivalent to the M51977 with externally re-settable OVP(over voltage protection)circuit.

**FEATURES**

- 500kHz operation to MOS FET
  - Output current .....  $\pm 2A$
  - Output rise time 60ns, fall time 40ns
  - Modified totempole output method with small through current
- Compact and light-weight power supply
  - Small start-up current .....  $90\mu A$  typ.
  - Big difference between "start-up voltage" and "stop voltage" makes the smoothing capacitor of the power input section small.
  - Start-up threshold 16V, stop voltage 10V
  - Packages with high power dissipation are used to withstand the heat generated by the gate-drive current of MOS FET.
  - 16-pin DIP, 20-pin SOP 1.5W (at 25°C)
- Simplified peripheral circuit with protection circuit and built-in large-capacity totempole output
  - High-speed current limiting circuit using pulse-by-pulse method (Two systems of CLM+pin, CLM-pin)
  - Protection by intermittent operation of output over current ..... Timer protection circuit
  - Over-voltage protection circuit with an externally re-settable latch (OVP)
  - Protection circuit for output miss action at low supply voltage (UVLO)
- High-performance and highly functional power supply
  - Triangular wave oscillator for easy dead time setting

**APPLICATION**

Feed forward regulator, fly-back regulator

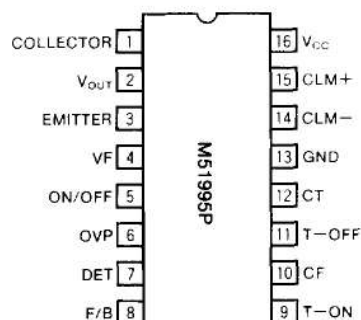
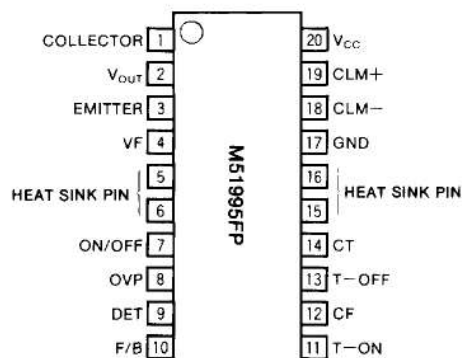
**RECOMMENDED OPERATING CONDITIONS**

Supply voltage range ..... 12~36V

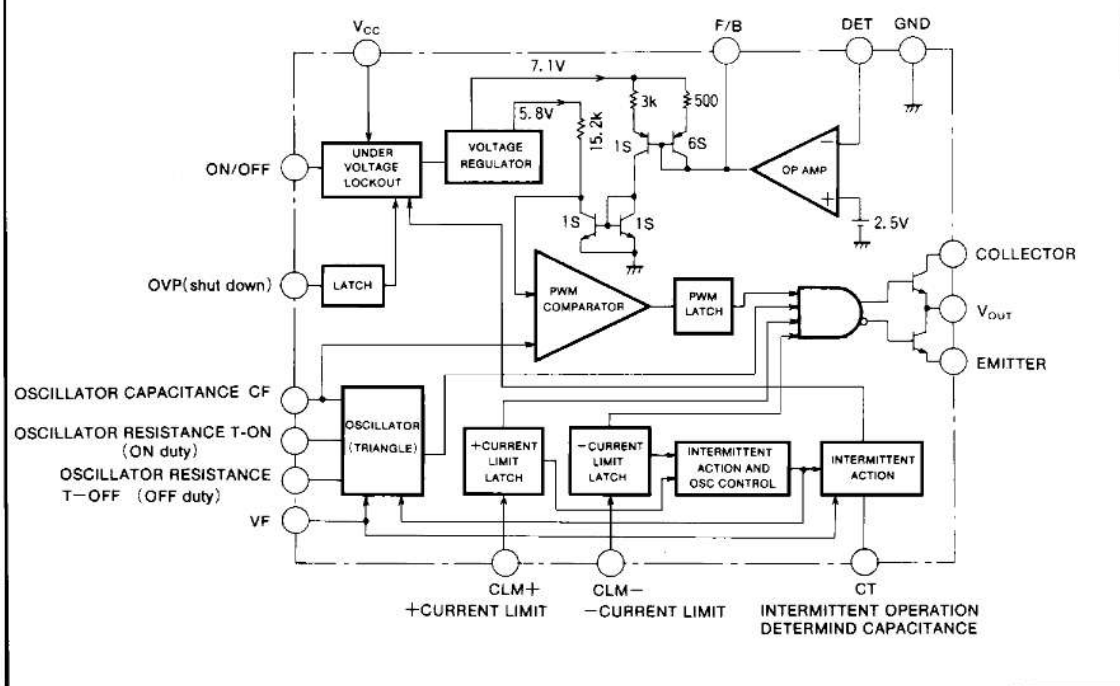
Operating frequency ..... less than 500kHz

Oscillator frequency setting resistance

- T-ON pin resistance  $R_{ON}$  ..... 10k~75k $\Omega$
- T-OFF pin resistance  $R_{OFF}$  ..... 2k~30k $\Omega$

**PIN CONFIGURATION (TOP VIEW)****Outline 16P4****Outline 20P2N-A**

Connect the heat sink pin to GND.

**SWITCHING REGULATOR CONTROL****BLOCK DIAGRAM****ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Conditions	Ratings	Unit
$V_{CC}$	Supply voltage		36	V
$V_C$	Collector voltage		36	V
$I_O$	Output current	Peak	$\pm 2$	A
		Continuous	$\pm 0.15$	A
$V_{VF}$	VF terminal voltage		$V_{CC}$	V
$V_{ON/OFF}$	ON/OFF terminal voltage		$V_{CC}$	V
$V_{CLM-}$	CLM- terminal voltage		$-4.0 \sim +4.0$	V
$V_{CLM+}$	CLM+ terminal voltage		$-0.3 \sim +4.0$	V
$I_{OVP}$	OVP terminal current		8	mA
$V_{DET}$	DET terminal voltage		6	V
$I_{DET}$	DET terminal input current		5	mA
$V_{FB}$	F/B terminal voltage		$0 \sim 10$	V
$I_{TON}$	T-ON terminal input current		-1	mA
$I_{TOFF}$	T-OFF terminal input current		-2	mA
$P_d$	Power dissipation	$T_a = 25^\circ\text{C}$	1.5	W
$K_\theta$	Thermal derating factor	$T_a > 25^\circ\text{C}$	12	mW/°C
$T_{opr}$	Operating temperature		$-30 \sim +85$	°C
$T_{stg}$	Storage temperature		$-40 \sim +125$	°C
$T_j$	Junction temperature		150	°C

- Note 1. "+" sign shows the direction of current flow into the IC and "-" sign shows the current flow from the IC.  
 2. This terminal has the constant voltage characteristic of 6~8V, when current is supplied from outside. The maximum allowable voltage is 6V when the constant voltage is applied to this terminal. And maximum allowable current into this terminal is 5mA.  
 3. The low impedance voltage supply should not be applied to the OVP terminal.

**SWITCHING REGULATOR CONTROL**

**ELECTRICAL CHARACTERISTICS** ( $V_{CC}=18V$ ,  $T_a=25^\circ C$ , unless otherwise noted)

Block	Symbol	Parameter	Test conditions	Limits			Unit
				Min	Typ	Max	
Supply voltage circuit current	$V_{CC}$	Operating supply voltage range		$V_{CC(STOP)}$	—	35	V
	$V_{CC(START)}$	Operation start up voltage		15.2	16.2	17.2	V
	$V_{CC(STOP)}$	Operation stop voltage		9.0	9.9	10.9	V
	$\Delta V_{CC}$	Difference voltage between operation start and stop	$\Delta V_{CC}=V_{CC(START)}-V_{CC(STOP)}$	5.0	6.3	7.6	V
	$I_{OCL}$	Stand-by current	$V_{CC}=14.5V$ , $T_a=25^\circ C$	50	90	140	$\mu A$
	$I_{CCO}$	Operating circuit current	$V_{CC}=14.5V$ , $-30 \leq T_a \leq 85^\circ C$	40	90	190	$\mu A$
	$I_{CC OFF}$	Circuit current in OFF state	$V_{CC}=30V$	10	15	21	mA
	$I_{CC CT}$	Circuit current in timer OFF state	$V_{CC}=25V$	0.95	1.31	5.0	mA
	$I_{CC CT}$	Circuit current in timer OFF state	$V_{CC}=14V$	50	90	140	$\mu A$
ON/OFF	$V_{THH ON/OFF}$	ON/OFF terminal high threshold voltage		2.1	2.6	3.1	V
	$V_{THL ON/OFF}$	ON/OFF terminal low threshold voltage		1.9	2.4	2.9	V
	$\Delta V_{THON/OFF}$	ON/OFF terminal hysteresis voltage		0.1	0.2	0.3	V
F/B	$I_{FBMIND}$	Current at 0% duty	F/B terminal input current	-2.1	-1.54	-1.0	mA
	$I_{FBMAXD}$	Current at maximum duty	F/B terminal input current	-0.90	-0.55	-0.40	mA
	$\Delta I_{FB}$	Current difference between max and 0% duty	$\Delta I_{FB}=I_{FBMIND}-I_{FBMAXD}$	-1.35	-0.99	-0.70	mA
	$V_{FB}$	Terminal voltage	F/B terminal input current=0.95mA	4.9	5.9	7.1	V
Detection	$R_{FB}$	Terminal resistance		420	600	780	$\Omega$
	$V_{DET}$	Detection voltage		2.4	2.5	2.6	V
	$I_{INDET}$	Input current of detection amp	$V_{DET}=2.5V$	—	1.0	3.0	$\mu A$
	$G_{AVDET}$	Voltage gain of detection amp		30	40	—	dB
OVP	$V_{THOVPH}$	OVP terminal H threshold voltage		540	750	960	mV
	$\Delta V_{THOVP}$	OVP terminal hysteresis voltage	$\Delta V_{THOVP}=V_{THOVPH}-V_{THOVPL}$		30		mV
	$I_{THOVP}$	OVP terminal threshold current		80	150	250	$\mu A$
	$I_{INOVP}$	OVP terminal input current	$V_{OVP}=400mV$	80	150	250	$\mu A$
	$V_{CCOVPC}$	OVP reset supply voltage		7.5	9.0	10.0	V
	$V_{CC(STOP)}-V_{CCOVPC}$	Difference supply voltage between operation stop and OVP reset	OVP terminal is open. (high impedance)	0.55	1.20	—	V
	$I_{THOVPC}$	Current from OVP terminal for OVP reset	$V_{CC}=30V$ $V_{CC}=18V$	-480 -210	-320 -140	-213 -93	$\mu A$
	$I_{THOVPC}$	Current from OVP terminal for OVP reset	$V_{CC}=30V$ $V_{CC}=18V$	-480 -210	-320 -140	-213 -93	$\mu A$
Timer	$f_{TIMER}$	Timer frequency	$C_T=4.7\mu F$	0.27	0.40	0.60	Hz
	$I_{TIMECH}$	Timer charge current	$V_{CT}=3.3V$ , $T_a=-5^\circ C$	-193	-138	-102	$\mu A$
	$I_{TIMECH}$	Timer charge current	$T_a=25^\circ C$ $T_a=85^\circ C$	-178 -147	-127 -105	-94 -78	$\mu A$
CLM—	$TIME_{OFF/ON}$	OFF time/ON time ratio		7.0	8.7	11.0	—
	$V_{THCLM-}$	CLM—terminal threshold voltage	$-5 \leq T_a \leq 85^\circ C$	-220	-200	-180	mV
	$I_{INCLM-}$	CLM—terminal current	$V_{CLM-}=-0.1V$	-170	-125	-90	$\mu A$
CLM+	$T_{PDCLM-}$	Delay time from CLM— to $V_{OUT}$		—	170	—	ns
	$V_{THCLM+}$	CLM+terminal threshold voltage	$-5 \leq T_a \leq 85^\circ C$	180	200	220	mV
	$I_{INCLM+}$	CLM+terminal current	$V_{CLM+}=0V$	-270	-205	-140	$\mu A$
	$T_{PDCLM+}$	Delay time from CLM+ to $V_{OUT}$		—	130	—	ns

**SWITCHING REGULATOR CONTROL**

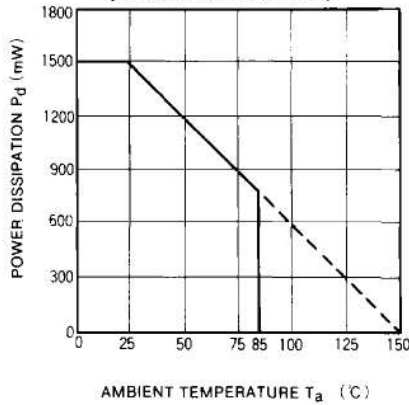
**ELECTRICAL CHARACTERISTICS** ( $V_{CC}=18V$ ,  $T_A=25^\circ C$ , unless otherwise noted)(CONTINUE)

Block	Symbol	Parameter	Test conditions	Limits			Unit
				Min	Typ	Max	
Oscillator	$f_{OSC}$	Oscillating frequency	$R_{ON}=20k\Omega$ , $R_{OFF}=17k\Omega$ $C_F=220pF$ , $-5 \leq T_A \leq 85^\circ C$	170	188	207	kHz
	$T_{DUTY}$	Maximum ON duty		47.0	50.0	53.0	%
	$V_{OSCH}$	Upper limit voltage of oscillation waveform	$f_{OSC}=188kHz$	3.97	4.37	4.77	V
	$V_{OSCL}$	Lower limit voltage of oscillation waveform	$f_{OSC}=188kHz$	1.76	1.96	2.16	V
	$\Delta V_{OSC}$	Voltage difference between upper limit and lower limit of OSC waveform	$f_{OSC}=188kHz$	2.11	2.41	2.71	V
VF	$f_{OSCVF}$	OSC frequency in CLM operating state	$V_F=5V$ $V_F=2V$ $R_{ON}=20k\Omega$ , $R_{OFF}=17k\Omega$ $C_F=220pF$	170 108	188 124	207 143	kHz
	$T_{VFDUTY}$	Duty in CLM operating state	$V_F=0.2V$ Min off duty / Max on duty	11.0	13.7	22.0	—
	$V_{THTIME}$	VF voltage at timer operating start		2.7	3.0	3.3	V
	$I_{VF}$	VF terminal input current	Source current	—	2	6	$\mu A$
	$V_{OL1}$	Output low voltage	$V_{CC}=18V$ , $I_O=10mA$	—	0.05	0.4	V
Output	$V_{OL2}$		$V_{CC}=18V$ , $I_O=100mA$	—	0.7	1.4	V
	$V_{OL3}$		$V_{CC}=5V$ , $I_O=1mA$	—	0.69	1.0	V
	$V_{OL4}$		$V_{CC}=5V$ , $I_O=100mA$	—	1.3	2.0	V
	$V_{OH1}$	Output high voltage	$V_{CC}=18V$ , $I_O=-10mA$	16.0	16.5	—	V
	$V_{OH2}$		$V_{CC}=18V$ , $I_O=-100mA$	15.5	16.0	—	V
	$T_{RISE}$	Output voltage rise time	No load	—	50	—	ns
	$T_{FALL}$	Output voltage fall time	No load	—	35	—	ns

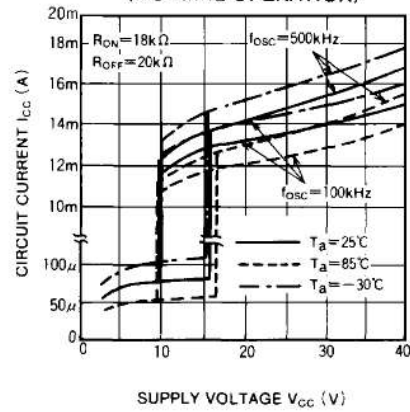
**SWITCHING REGULATOR CONTROL**

**TYPICAL CHARACTERISTICS**

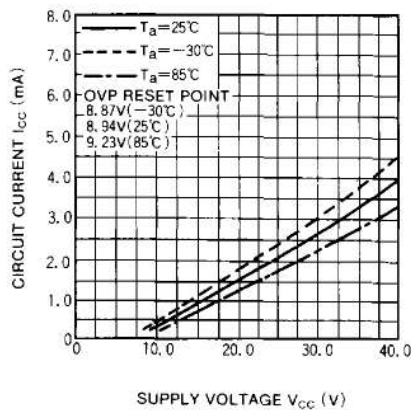
**THERMAL DERATING  
(MAXIMUM RATING)**



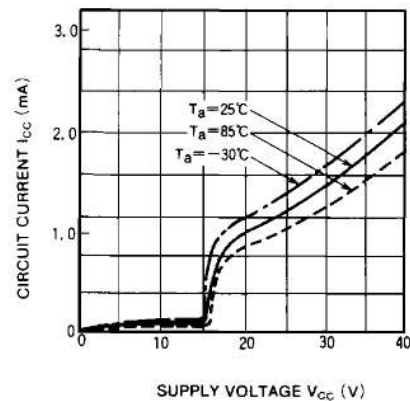
**CIRCUIT CURRENT VS. SUPPLY VOLTAGE  
(NORMAL OPERATION)**



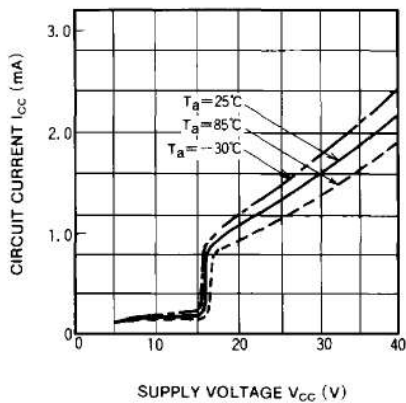
**CIRCUIT CURRENT VS. SUPPLY VOLTAGE  
(OVP OPERATION)**



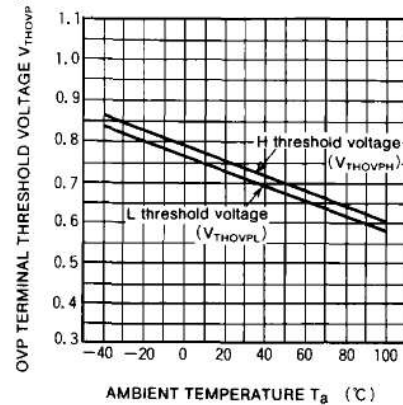
**CIRCUIT CURRENT VS. SUPPLY VOLTAGE  
(OFF STATE)**



**CIRCUIT CURRENT VS. SUPPLY VOLTAGE  
(TIMER OFF STATE)**

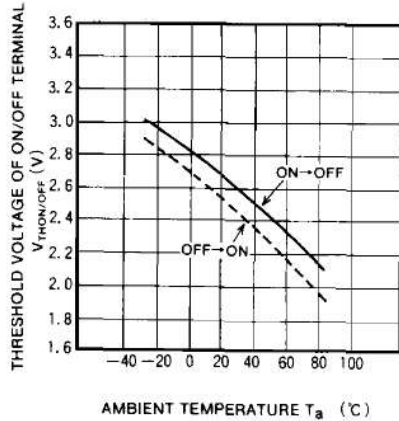


**OVP TERMINAL THRESHOLD VOLTAGE  
VS. AMBIENT TEMPERATURE**

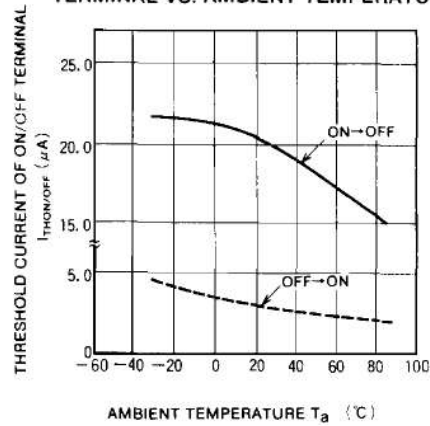


**SWITCHING REGULATOR CONTROL**

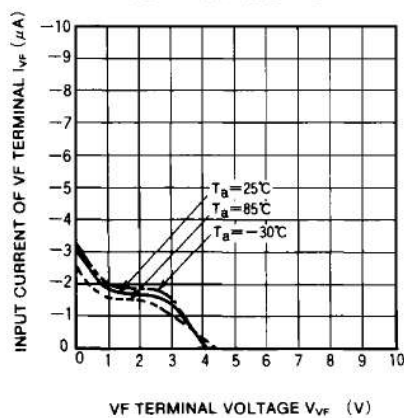
**THRESHOLD VOLTAGE OF ON/OFF TERMINAL VS. AMBIENT TEMPERATURE**



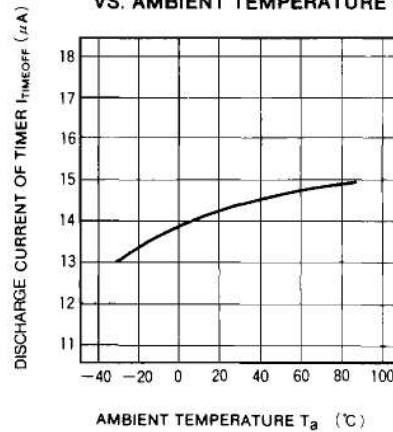
**THRESHOLD CURRENT OF ON/OFF TERMINAL VS. AMBIENT TEMPERATURE**



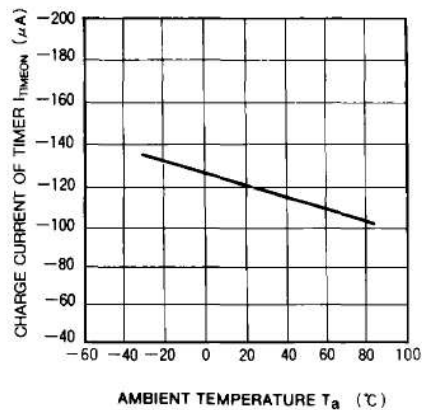
**INPUT CURRENT OF VF TERMINAL VS. INPUT VOLTAGE**



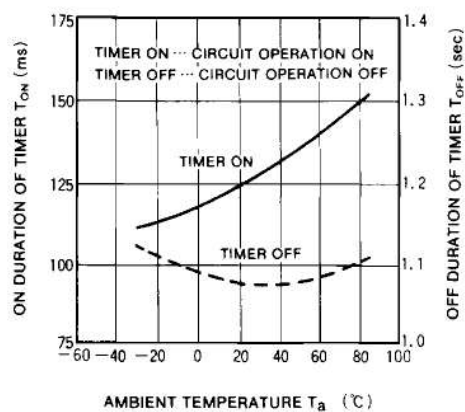
**DISCHARGE CURRENT OF TIMER VS. AMBIENT TEMPERATURE**



**CHARGE CURRENT OF TIMER VS. AMBIENT TEMPERATURE**

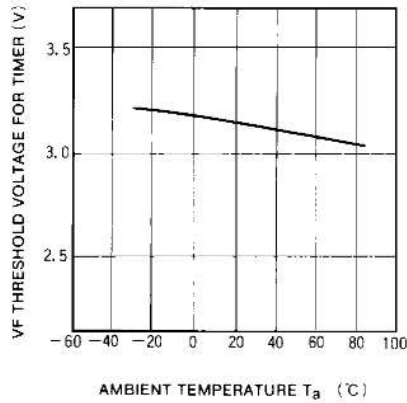


**ON AND OFF DURATION OF TIMER VS. AMBIENT TEMPERATURE (INTERMITTENT OPERATION)**

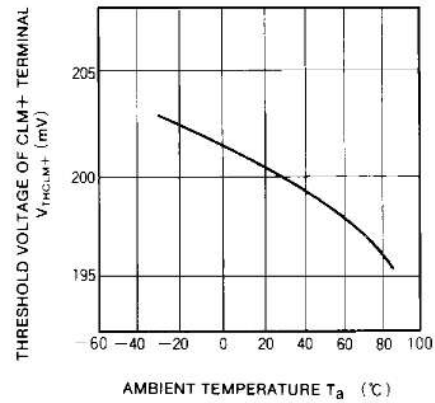


**SWITCHING REGULATOR CONTROL**

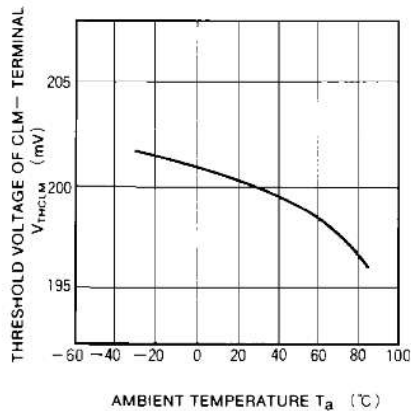
**VF THRESHOLD VOLTAGE FOR TIMER  
VS. AMBIENT TEMPERATURE**



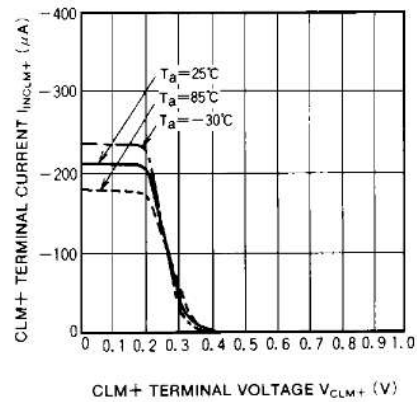
**THRESHOLD VOLTAGE OF CLM+ TERMINAL  
VS. AMBIENT TEMPERATURE**



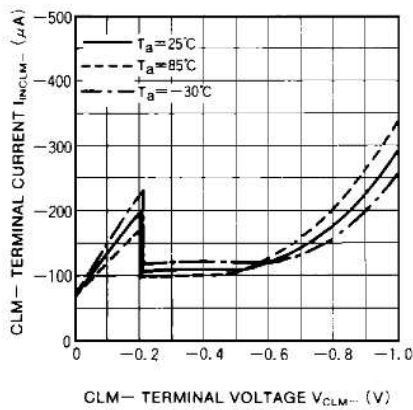
**THRESHOLD VOLTAGE OF CLM- TERMINAL  
VS. AMBIENT TEMPERATURE**



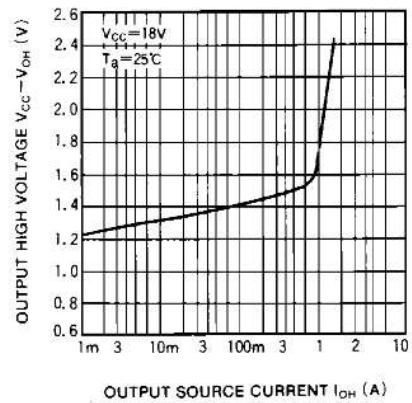
**CLM+ TERMINAL CURRENT  
VS. CLM+ TERMINAL VOLTAGE**



**CLM- TERMINAL CURRENT  
VS. CLM- TERMINAL VOLTAGE**

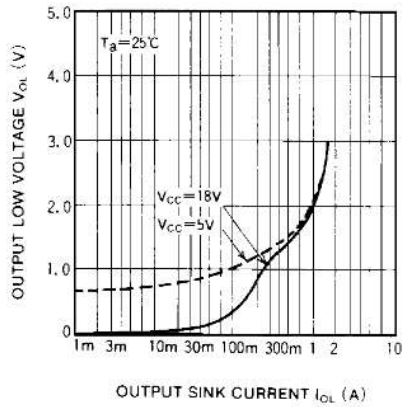


**OUTPUT HIGH VOLTAGE VS.  
OUTPUT SOURCE CURRENT**

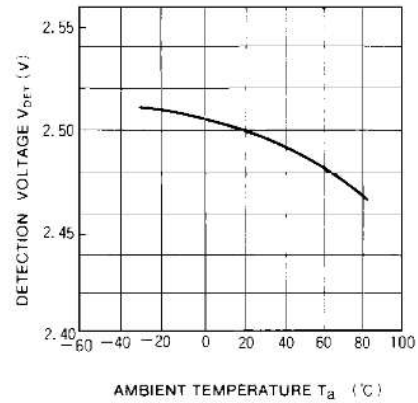


**SWITCHING REGULATOR CONTROL**

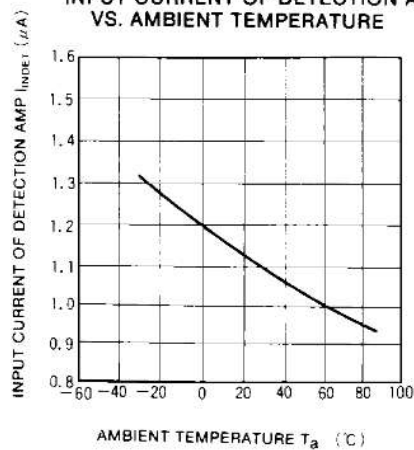
**OUTPUT LOW VOLTAGE VS.  
OUTPUT SINK CURRENT**



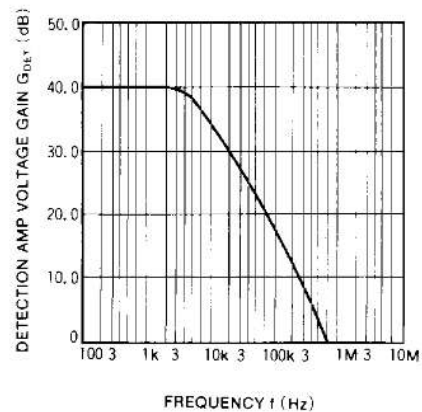
**DETECTION VOLTAGE VS.  
AMBIENT TEMPERATURE**



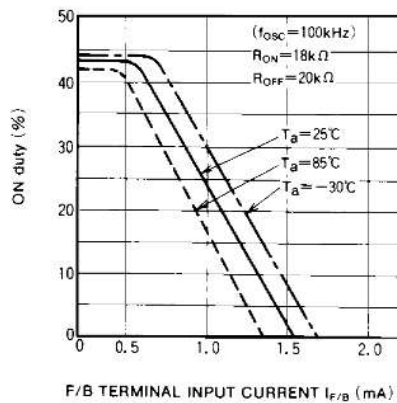
**INPUT CURRENT OF DETECTION AMP  
VS. AMBIENT TEMPERATURE**



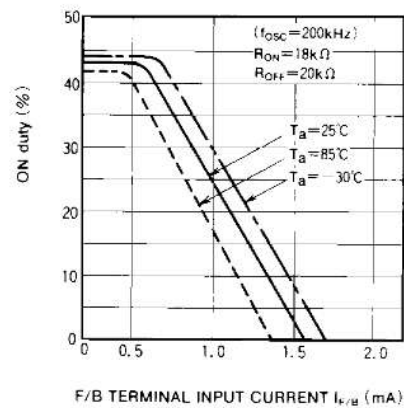
**DETECTION AMP VOLTAGE GAIN  
VS. FREQUENCY**



**ON duty VS. F/B TERMINAL  
INPUT CURRENT**



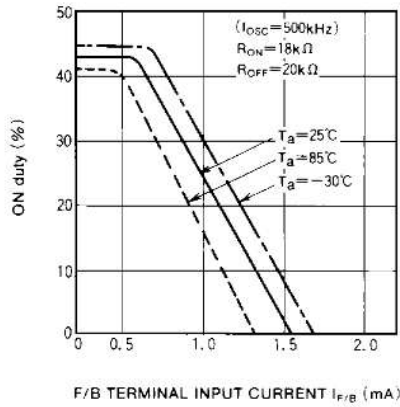
**ON duty VS. F/B TERMINAL  
INPUT CURRENT**



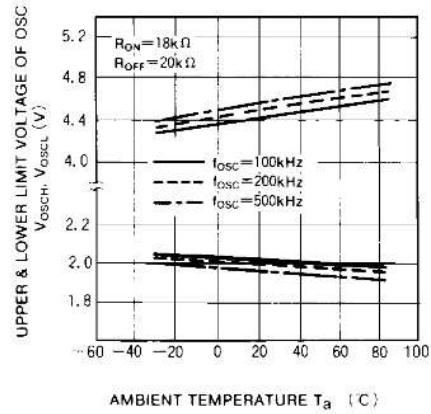


**SWITCHING REGULATOR CONTROL**

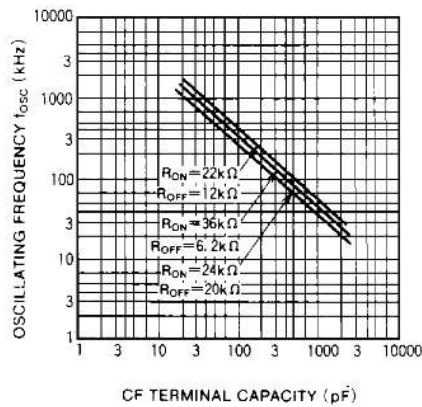
**ON duty VS. F/B TERMINAL INPUT CURRENT**



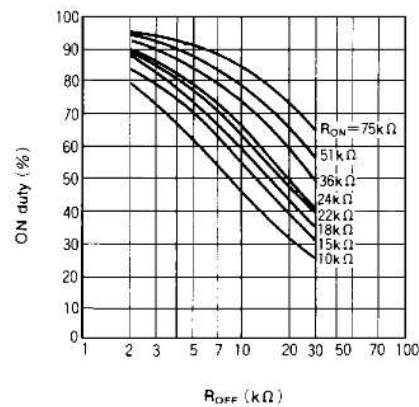
**UPPER & LOWER LIMIT VOLTAGE OF OSC VS. AMBIENT TEMPERATURE**



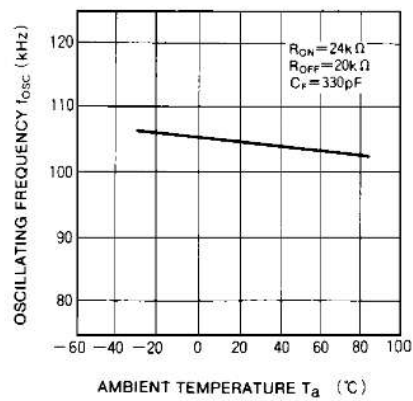
**OSCILLATING FREQUENCY VS. CF TERMINAL CAPACITY**



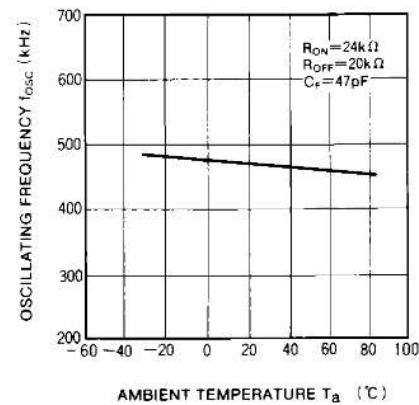
**ON duty VS.  $R_{OFF}$**



**OSCILLATING FREQUENCY VS. AMBIENT TEMPERATURE**

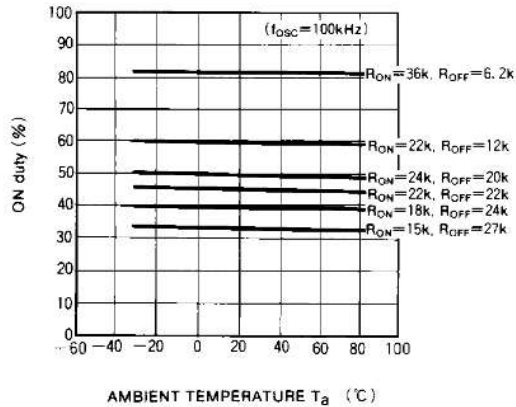


**OSCILLATING FREQUENCY VS. AMBIENT TEMPERATURE**

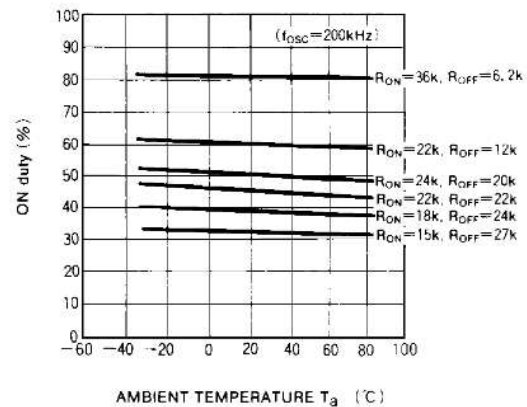


**SWITCHING REGULATOR CONTROL**

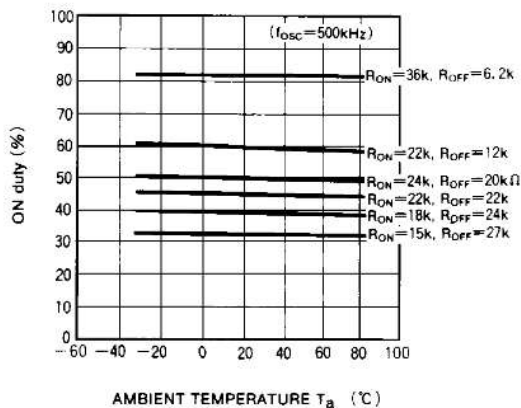
ON duty VS.  
AMBIENT TEMPERATURE



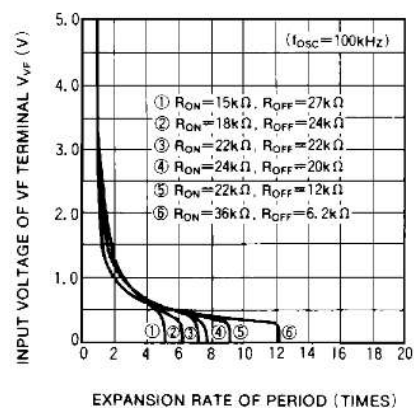
ON duty VS.  
AMBIENT TEMPERATURE



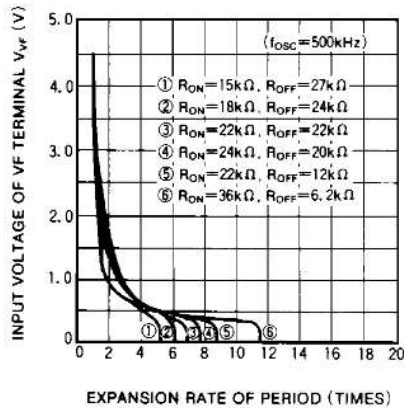
ON duty VS.  
AMBIENT TEMPERATURE



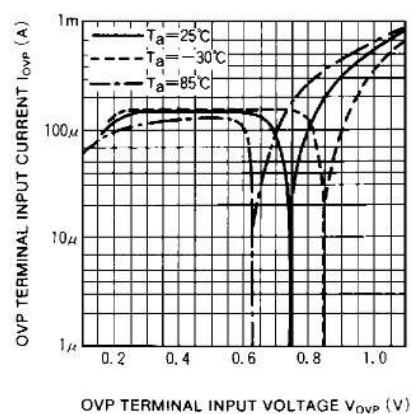
INPUT VOLTAGE OF VF TERMINAL VS.  
EXPANSION RATE OF PERIOD



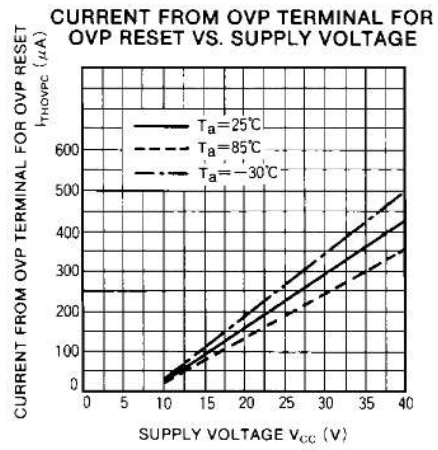
INPUT VOLTAGE OF VF TERMINAL VS.  
EXPANSION RATE OF PERIOD



OVP TERMINAL INPUT VOLTAGE VS.  
INPUT CURRENT



**SWITCHING REGULATOR CONTROL**



**SWITCHING REGULATOR CONTROL**

**FUNCTION DESCRIPTION**

Type M51995P and M51995FP are especially designed for off-line primary PWM control IC of switching mode power supply (SMPS) to get DC voltage from AC power supply. Using this IC, smart SMPS can be realized with reasonable cost and compact size as the number of external electric

parts can be reduced and also parts can be replaced by reasonable one.

In the following circuit diagram, MOS-FET is used for output transistor, however bipolar transistor can be used with no problem.

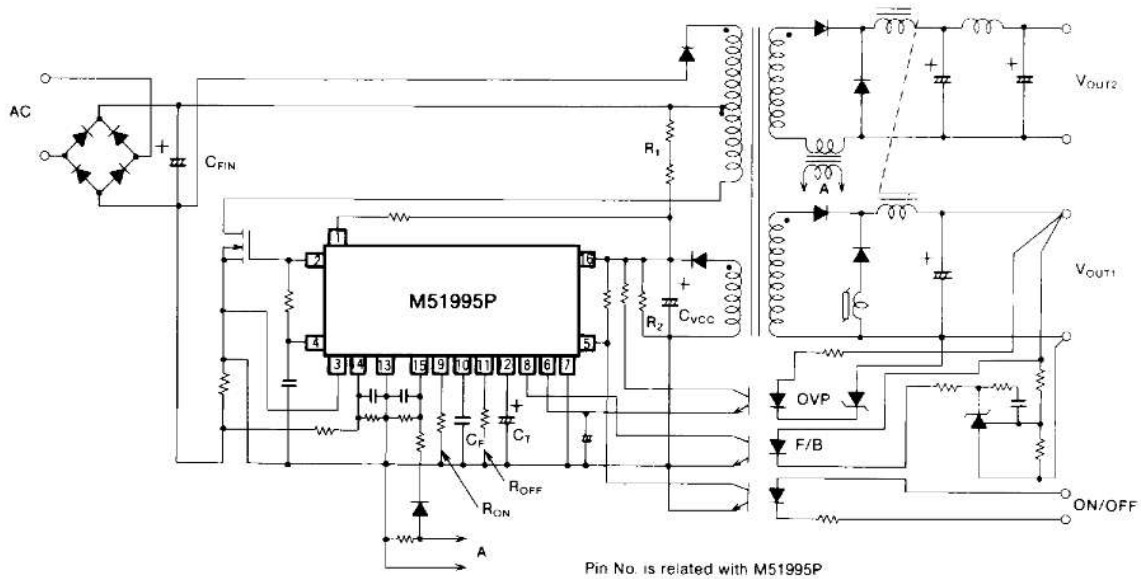


Fig. 1 Example application circuit diagram of feed forward regulator

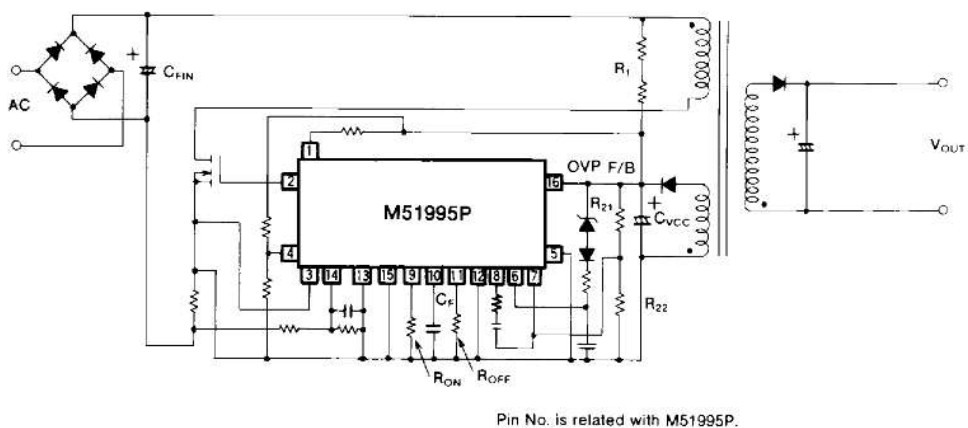


Fig. 2 Example application circuit diagram of fly-back regulator

**SWITCHING REGULATOR CONTROL**

**Start-up circuit section**

The start-up current is such low current level as typical 90 $\mu$ A, as shown in Fig. 3, when the  $V_{CC}$  voltage is increased from low level to start-up voltage  $V_{CC(START)}$ . In this voltage range, only a few parts in this IC, which has the function to make the output voltage low level, is alive and  $I_{CC}$  current is used to keep output low level. The large voltage difference between  $V_{CC(START)}$  and  $V_{CC(STOP)}$  makes start-up easy, because it takes rather long duration from  $V_{CC(START)}$  to  $V_{CC(STOP)}$ .

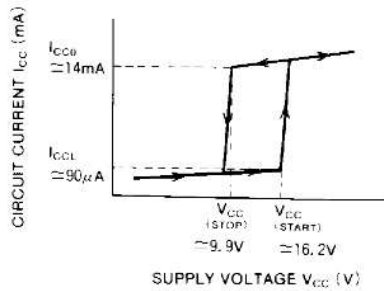


Fig. 3 Circuit current vs. supply voltage

**Oscillator section**

The oscillation waveform is the triangle one. The ON-duration of output pulse depends on the rising duration of the triangle waveform and dead-time is decided by the falling duration.

The rising duration is determined by the product of external resistor  $R_{ON}$  and capacitor  $C_F$  and the falling duration is mainly determined by the product of resistor  $R_{OFF}$  and capacitor  $C_F$ .

**(1) Oscillator operation when intermittent action and OSC control circuit does not operate**

Fig. 4 shows the equivalent charging and discharging circuit diagram of oscillator when the current limiting circuit does not operate. It means that intermittent action and OSC control circuit does not operate.

The current flows through  $R_{ON}$  from the constant voltage source of 5.8V.  $C_F$  is charged up by the same amplitude as  $R_{ON}$  current, when internal switch  $SW_1$  is switched to "charging side". The rise rate of CF terminal is given as

$$\approx \frac{V_{T-ON}}{R_{ON} \times C_F} \quad (V/s) \quad (1)$$

where  $V_{T-ON} \approx 4.5V$

The maximum on duration is approximately given as

$$\approx \frac{(V_{OSCH} - V_{OSCL}) \times R_{ON} \times C_F}{V_{T-ON}} \quad (s) \quad (2)$$

where  $V_{OSCH} \approx 4.4V$   
 $V_{OSCL} \approx 2.0V$

$C_F$  is discharged by the summed-up of  $R_{OFF}$  current and one sixteenth (1/16) of  $R_{ON}$  current by the function of  $Q_2$ ,  $Q_3$  and  $Q_4$  when  $SW_1$ ,  $SW_2$  are switched to "discharge side".

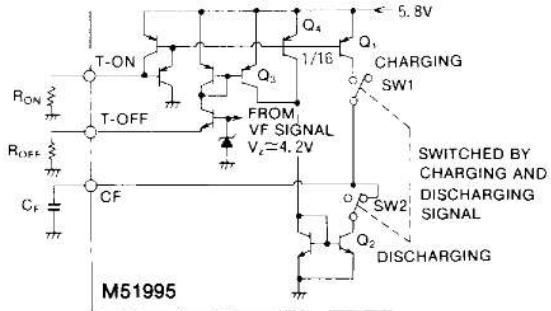


Fig. 4 Schematic diagram of charging and discharging control circuit for OSC. capacitor  $C_F$

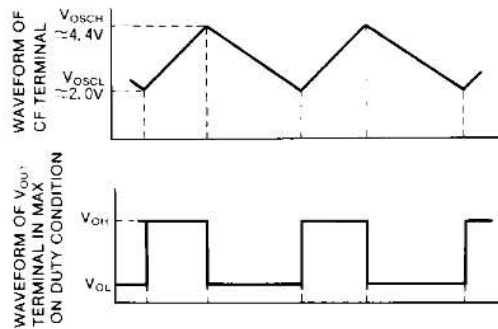


Fig. 5 OSC. waveform at normal condition (no-operation of intermittent action and OSC. control circuit)

So fall rate of CF terminal is given as

$$\approx \frac{V_{T-OFF}}{R_{OFF} \times C_F} + \frac{V_{T-ON}}{16 \times R_{ON} \times C_F} \quad (V/s) \quad (3)$$

The minimum off duration approximately is given as

$$\approx \frac{(V_{OSCH} - V_{OSCL}) \times C_F}{\frac{V_{T-OFF}}{R_{OFF}} + \frac{V_{T-ON}}{16 \times R_{ON}}} \quad (s) \quad (4)$$

where  $V_{T-OFF} \approx 3.5V$

The cycle time of oscillation is given by the summation of Equations 2 and 4.

The frequency including the dead-time is not influenced by the temperature because of the built-in temperature compensating circuit.

## SWITCHING REGULATOR CONTROL

## (2) Oscillator operation when intermittent action and OSC control circuit operates.

When over current signal is applied to CLM+ or CLM- terminal, and the current limiting circuit, intermittent action and OSC control circuit starts to operate. In this case T-OFF terminal voltage depends on VF terminal voltage, so the oscillation frequency decreases and dead-time spreads.

The rise rate of oscillation waveform is given as

$$\approx \frac{V_{T-ON}}{R_{ON} \times C_F} \quad (V/s) \quad (5)$$

The fall rate of oscillation waveform is given as

$$\approx \frac{V_{VF} - V_{VFO}}{R_{OFF} \times C_F} + \frac{V_{T-ON}}{16 \times R_{ON} \times C_F} \quad (V/s) \quad (6)$$

where  $V_{T-ON} \approx 4.5V$   
 $V_{VF}$ : VF terminal voltage  
 $V_{VFO} \approx 0.4V$   
 $V_{VF} - V_{VFO} = 0$  if  $V_{VF} - V_{VFO} < 0$   
 $V_{VF} - V_{VFO} = V_{T-OFF}$  if  $V_{VF} - V_{VFO} > V_{T-OFF} \approx 3.5V$

So when  $V_{VF} > 3.5V$ , the operation is just same as that in the no current limiting operation state.

The maximum on-duration is just same as that in the no-operation state of intermittent and oscillation control circuit and is given as follows;

$$\approx \frac{(V_{OSCH} - V_{OSCL}) \times R_{ON} \times C_F}{V_{T-ON}} \quad (s) \quad (7)$$

The minimum off-duration is approximately given as ;

$$\approx \frac{(V_{OSCH} - V_{OSCL}) \times C_F}{\frac{V_{VF} - V_{VFO}}{R_{OFF} \times C_F} + \frac{V_{T-ON}}{16 \times R_{ON} \times C_F}} \quad (s) \quad (8)$$

The oscillation period is given by the summation of Equation (7) and (8).

As shown in Fig. 7, the internal circuit kills the first output pulse in the output waveform. The output waveform will appear from the second pulse cycle because the duration of first cycle takes  $C_F$  charging time longer comparing with that at the stable operating state.

Usually the applied voltage to VF terminal must be proportional the output voltage of the regulator.

So when the over current occurs and the output voltage of the regulator becomes low, the off-duration becomes wide. There are two methods to get the control voltage, which depends on the output voltage, on primary side. For the fly back type regulator application, the induced voltage on the third or bias winding is dependent on output voltage. On the other hand, for the feed forward type regulator application, it can be used that the output voltage depends on the product of induced voltage and "on-duty", as the current of

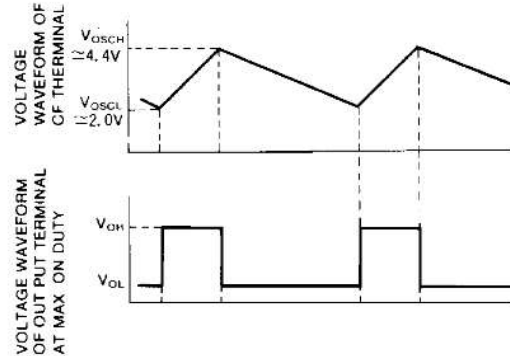


Fig. 6 OSC. waveform with operation of intermittent and OSC. control circuit operation

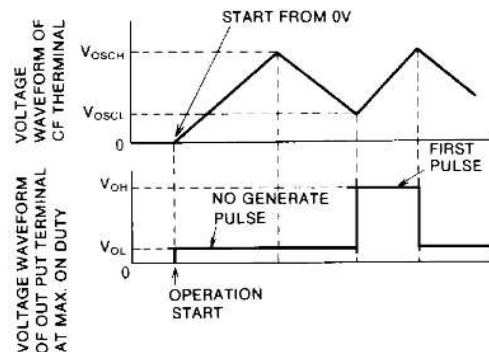


Fig. 7 Relation between OSC. and output waveform circuit operation at start up

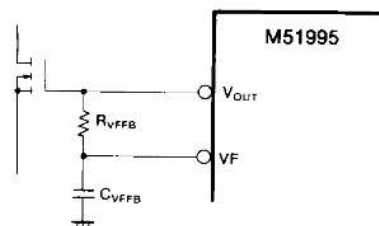


Fig. 8 Feedback loop with low pass filter from output to VF terminal

choke coil will continue at over load condition, it means the "continuous current" condition.

Fig. 8 shows one of the examples for VF terminal application for the feed forward type regulator.

**SWITCHING REGULATOR CONTROL**

**PWM comparator and PWM latch section**

Fig. 9 shows the PWM comparator and latch section. The on-duration of output waveform coincides with the rising duration of CF terminal waveform, when the infinite resistor is connected between F/B terminal and GND.

When the F/B terminal has finite impedance and current flows out from F/B terminal, "A" point potential shown in Fig. 9 depends on this current. So the "A" point potential is close to GND level when the flow-out current becomes large.

"A" point potential is compared with the CF terminal oscillator waveform and PWM comparator, and the latch circuit is set when the potential of oscillator waveform is higher than "A" point potential.

On the other hand, this latch circuit is reset by high level signal during the deadtime of oscillation (falling duration of oscillation waveform). So the "B" point potential or output waveform of latch circuit is the one shown in Fig. 10.

The final output waveform or "C" point potential is got by combining the "B" point signal and dead-time signal logically. (please refer to Fig. 10)

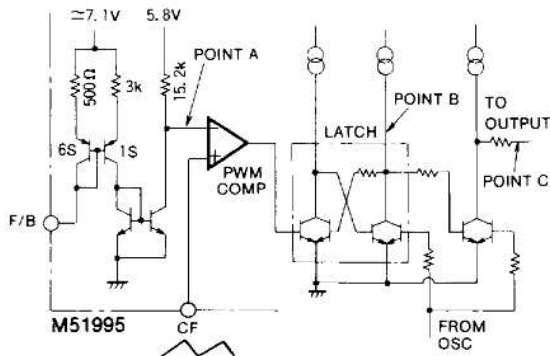


Fig. 9 PWM comparator and latch circuit

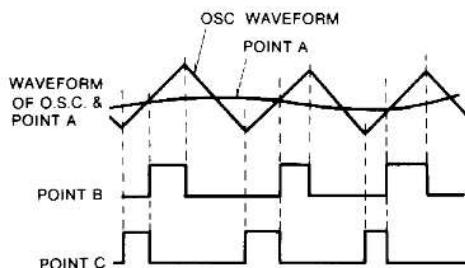


Fig. 10 Waveforms of PWM comparator Input point A, latch circuit points B and C

**Current limiting section**

When the current-limit signal is applied before the crossing instant of "A" point potential and CF terminal voltage shown in Fig. 9, this signal makes the output "off" and the off state will continue until next cycle. Fig. 11 shows the timing relation among them.

The current limiting circuit has two input terminals, one has the detector-sensitivity of +200mV to the GND terminal and the other has -200mV. The circuit will be latched if the input signal is over the limit of either terminal.

If the current limiting circuit is set, no waveform is generated at output terminal however this state is reset during the succeeding dead-time.

So this current limiting circuit is able to have the function in every cycle, and is named "pulse-by-pulse current limit".

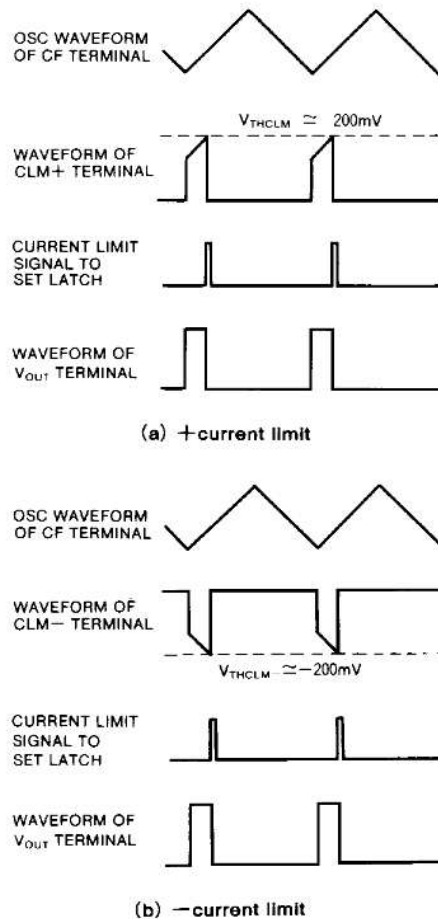


Fig. 11 Operating waveforms of current limiting circuit

It is rather recommended to use not "CLM+" but "CLM-" terminal, as the influence from the gate drive current of MOS-FET can be eliminated and wide voltage rating of +

**SWITCHING REGULATOR CONTROL**

4V to -4V is guaranteed for absolute maximum rating. There happen some noise voltage on  $R_{CLM}$  during the switching of power transistor due to the snubber circuit and stray capacitor of the transformer windings.

To eliminate the abnormal operation by the noise voltage, the low pass filter, which consists of  $R_{NF}$  and  $C_{NF}$  is used as shown in Fig. 12.

It is recommended to use  $10 \sim 100 \Omega$  for  $R_{NF}$  because such range of  $R_{NF}$  is not influenced by the flow-out current of some  $200 \mu A$  from CLM terminal and  $C_{NF}$  is designed to have the enough value to absorb the noise voltage.

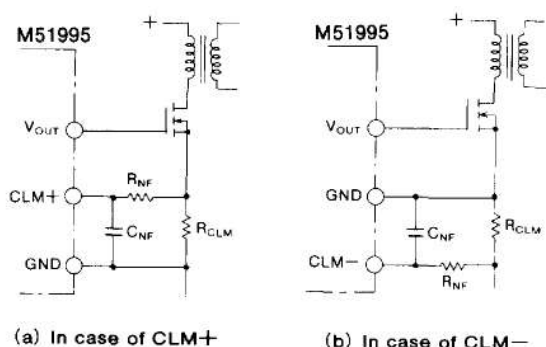


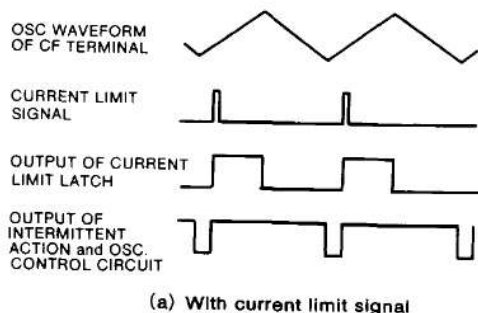
Fig. 12 How to connect current limit circuit

**Intermittent action and oscillation control section**

When the internal current limiting circuit starts to operate and also the VF level decreases to lower than the certain level of some 3V, the dead-time spreads and intermittent action and OSC control circuit (which is one of the timer-type-protection circuit) starts to operate.

The intermittent action and OSC control circuit is the one to generate the control signal for oscillator and intermittent action circuit.

Fig.13 shows the timing-chart of this circuit. When the output of intermittent action and oscillation control is at "high" level, the waveform of oscillator depends on the VF terminal voltage and the intermittent action circuit begins to operate.



(a) With current limit signal

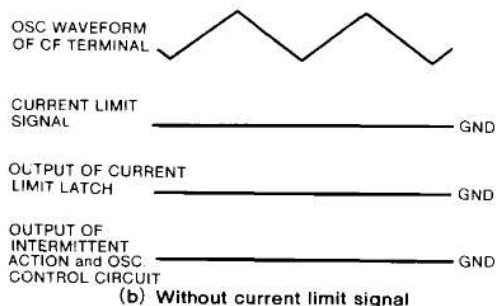


Fig. 13 Timing chart of intermittent and OSC. control circuit

**Intermittent action circuit section**

Intermittent action circuit will start to operate when the output signal from the intermittent action and oscillation control circuit are "high" and also VF terminal voltage is lower than  $V_{THTIME}$  of about 3V.

Fig. 14 shows the block diagram of intermittent action circuit. Transistor Q is on state when VF terminal voltage is higher than  $V_{THTIME}$  of about 3V, so the CT terminal voltage is near to GND potential.

When VF terminal voltage is lower than  $V_{THTIME}$ , Q becomes "off" and the CT has the possibility to be charged up.

Under this condition, if the intermittent action and oscillation control signal become "high", the switch  $SW_A$  will close only in this "high" duration and  $C_T$  is charged up by the current of  $120 \mu A$  through  $SW_A$  ( $SW_B$  is open) and CT terminal potential will rise. The output pulse can be generated only in this duration..

When the CT terminal voltage reaches to 8V, the control logic circuit makes the  $SW_A$  "off" and  $SW_B$  "on", in order to flow in the  $I_{TIMEOFF}$  of  $15 \mu A$  to CT terminal.

The IC operation will be ceased in the falling duration.

On the other hand, when CT terminal voltage decreases to lower than 2V, the IC operation will be reset to original state, as the control logic circuit makes the  $SW_A$  "on" and  $SW_B$  "off".

Therefore the parts in power circuit including secondary rectifier diodes are protected from the overheat by the over current.

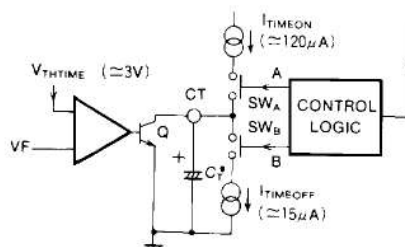


Fig. 14 Block diagram of intermittent action circuit



# SWITCHING REGULATOR CONTROL

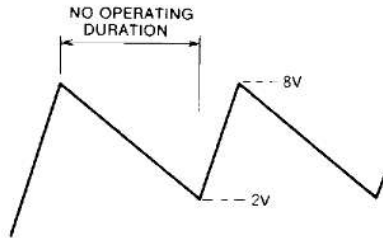


Fig. 15 Waveform of CT terminal

Fig. 16 shows the  $I_{CC}$  versus  $V_{CC}$  in this timer-off duration. In this duration the power is not supplied to IC from the third winding of transformer but through from the resistor  $R_1$  connected to  $V_{CC}$  line. If the  $R_1$  shown in Fig. 1 and 2 is selected adequate value,  $V_{CC}$  terminal voltage will be kept at not so high or low but adequate value, as the  $I_{CC}$  versus  $V_{CC}$  characteristics has such the one shown in Fig. 16.

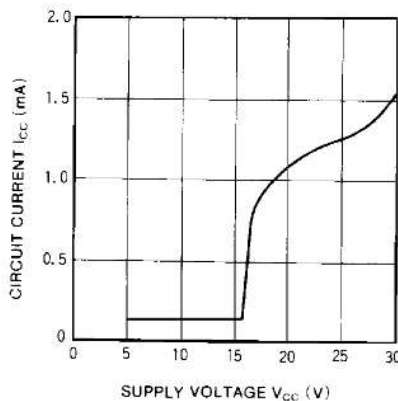


Fig. 16  $I_{CC}$  vs.  $V_{CC}$  in timer-off duration of intermittent action circuit

To ground the CT terminal is recommended, when the intermittent mode is not used.

In this case the oscillated frequency will become low but the IC will neither stop the oscillation nor change to the intermittent action mode, when the current limit function becomes to operate and the VF terminal voltage becomes low.

## Voltage detector circuit (DET) section

The DET terminal can be used to control the output voltage which is determined by the winding ratio of fly back transformer in fly-back system or in case of common ground cir-

cuit of primary and secondary in feed forward system.

The circuit diagram is quite similar to that of shunt regulator type 431 as shown in Fig. 17. As well known from Fig. 17 and Fig. 18, the output of OP AMP has the current-sink ability, when the DET terminal voltage is higher than 2.5V but it becomes high impedance state when lower than 2.5V DET terminal and F/B terminal have inverting phase characteristics each other, so it is recommended to connect the resistor and capacitor in series between them for phase compensation. It is very important, one can not connect by resistor directly as there is the voltage difference between them and the capacitor has the DC stopper function.

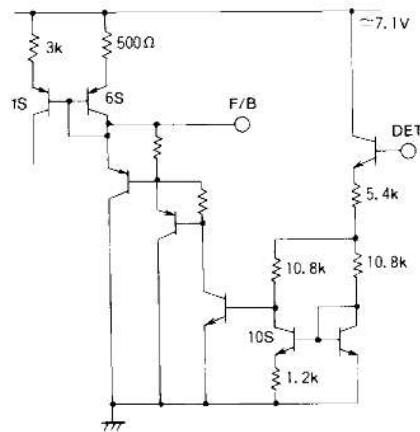


Fig. 17 Equivalent circuit diagram of voltage detector

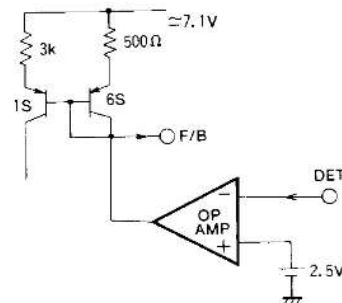


Fig. 18 Equivalent circuit diagram of voltage detector

## ON-OFF circuit section

Fig. 19 shows the circuit diagram of ON-OFF circuit. The current flown into the ON/OFF terminal makes the  $Q_4$  "on" and the switching operation stop. On the other hand, the switching operation will recover as no current flown into ON/OFF terminal makes  $Q_4$  "off". As the constant current source connected to  $Q_4$  base terminal has such the hyster-

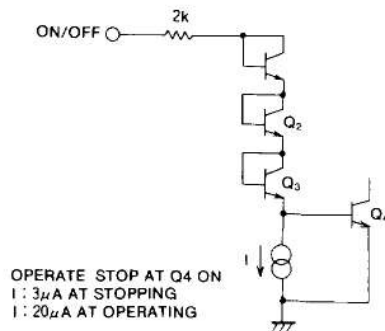
**SWITCHING REGULATOR CONTROL**

is characteristics of  $20\mu\text{A}$  at operation and  $3\mu\text{A}$  at stop-  
ping. So the unstable operation is not appeared even if the  
ON/OFF terminal voltage signal varies slowly.

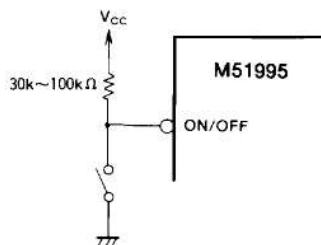
Fig. 20 shows how to connect the ON/OFF terminal. The  
switching operation will stop by switch-off and operate by  
switch-on.

Transistor or photo transistor can be replaced by this  
switch, of course. No resistor of  $30\sim 100\text{k}\Omega$  is connected  
and ON/OFF terminal is directly connected to GND, when  
it is not necessary to use the ON/OFF operation.

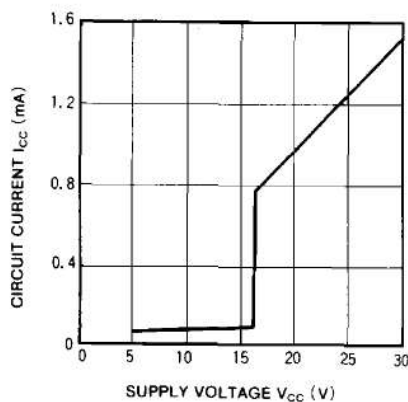
Fig. 21 shows the  $I_{CC}$  versus  $V_{CC}$  characteristics in OFF  
state and  $V_{CC}$  will be kept at not so high or low but at the  
adequate voltage, when  $R_1$  shown in Fig. 1 and 2 is  
selected properly.



**Fig. 19 ON/OFF circuit**



**Fig. 20 Connecting of ON/OFF terminal**



**Fig. 21  $I_{CC}$  vs.  $V_{CC}$  in OFF state**

**OVP circuit (over voltage protection circuit)  
section**

OVP circuit is basically positive feedback circuit con-  
structed by  $Q_2$ ,  $Q_3$  as shown in Fig. 22.

$Q_2$ ,  $Q_3$  turn on and the circuit operation of IC stops, when  
the input signal is applied to OVP terminal. (threshold vol-  
tage  $\approx 750\text{mV}$ )

The current value of  $I_2$  is about  $150\mu\text{A}$  when the OVP does  
not operates but it decreases to about  $2\mu\text{A}$  when OVP  
operates.

It is necessary to input the sufficient larger current ( $800\mu\text{A}$   
 $\sim 8\text{mA}$ ) than  $I_2$  for triggering the OVP operation.

The reason to decrease  $I_2$  is that it is necessary that  $I_{CC}$  at  
the OVP reset supply voltage is small.

It is necessary that OVP state holds by circuit current from  
 $R_1$  in the application example, so this IC has the charac-  
teristic of small  $I_{CC}$  at the OVP reset supply voltage ( $\approx$  stand-  
by current  $+ 20\mu\text{A}$ )

On the other hand, the circuit current is large in the higher  
supply voltage, so the supply voltage of this IC doesn't be-  
come so high by the voltage drop across  $R_1$ .

This characteristic is shown in Fig. 23.

The OVP terminal input current in the voltage lower than  
the OVP threshold voltage is based on  $I_2$  and the input cur-  
rent in the voltage higher than the OVP threshold voltage is  
the sum of the current flowing to the base of  $Q_3$  and the  
current flowing from the collector of  $Q_2$  to the base.

For holding in the latch state, it is necessary that the OVP  
terminal voltage is kept in the voltage higher than  $V_{BE}$  of  
 $Q_3$ .

So if the capacitor is connected between the OVP terminal  
and GND, even though  $Q_2$  turns on in a moment by the  
surge voltage, etc, this latch action does not hold if the  
OVP terminal voltage does not become higher than  $V_{BE}$  of  
 $Q_3$  by charging this capacitor.

For resetting OVP state, it is necessary to make the OVP  
terminal voltage lower than the OVP L threshold voltage or  
make  $V_{CC}$  lower than the OVP reset supply voltage.

As the OVP reset voltage is settled on the rather high vol-  
tage of  $9.0\text{V}$ , SMPS can be reset in rather short time from  
the switch-off of the AC power source if the smoothing  
capacitor is not so large value.

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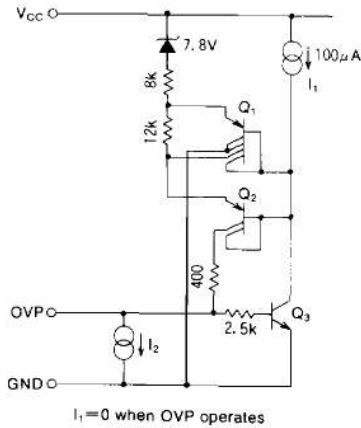


Fig. 22 Detail diagram of OVP circuit

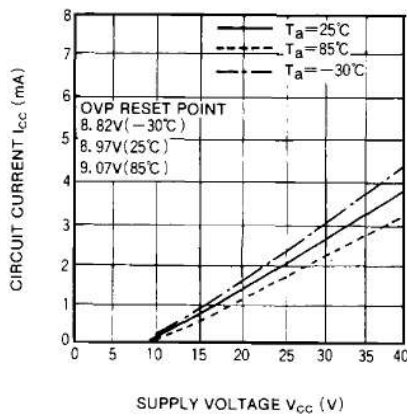


Fig. 23 CIRCUIT CURRENT VS SUPPLY VOLTAGE (OVP OPERATION)

**Output section**

It is required that the output circuit have the high sink and source abilities for MOS-FET drive. It is well known that the "totem-pole circuit has high sink and source ability. However, it has the demerit of high through current.

For example, the through current may reach such the high current level of 1A, if type M51995 has the "conventional" totem-pole circuit. For the high frequency application such as higher than 100kHz, this through current is very important factor and will cause not only the large  $I_{CC}$  current and the inevitable heat-up of IC but also the noise voltage.

This IC uses the improved totem-pole circuit, so without deteriorating the characteristic of operating speed, its through current is approximately 100mA.

**APPLICATION NOTE OF TYPE M51995P, FP**  
**Design of start-up circuit and the power supply of IC**

**(1)The start-up circuit when it is not necessary to set the start and stop input voltage**

Fig. 24 shows one of the example circuit diagram of the start-up circuit which is used when it is not necessary to set the start and stop voltage.

It is recommended that the current more than  $300\mu A$  flows through  $R_1$  in order to overcome the operation start-up current  $I_{CC(START)}$  and  $C_{VCC}$  is in the range of 10 to  $47\mu F$ . The product of  $R_1$  by  $C_{VCC}$  causes the time delay of operation, so the response time will be long if the product is too much large.

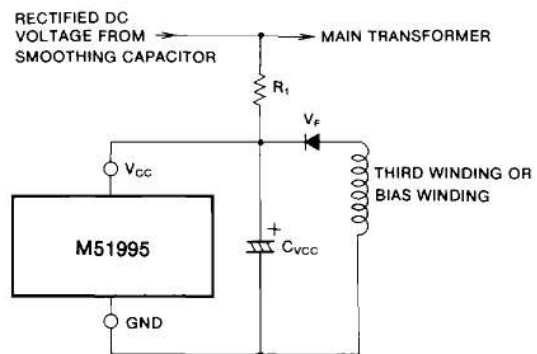


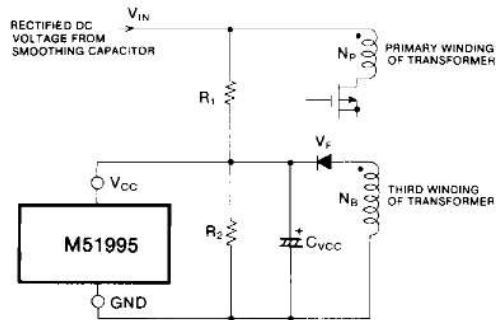
Fig. 24 Start-up circuit diagram when it is not necessary to set the start and stop input voltage

Just after the start-up, the  $I_{CC}$  current is supplied from  $C_{VCC}$ , however, under the steady state condition, IC will be supplied from the third winding or bias winding of transformer, the winding ratio of the third winding must be designed so that the induced voltage may be higher than the operation-stop voltage  $V_{CC(STOP)}$ .

The  $V_{CC}$  voltage is recommended to be 12V to 17V as the

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normal and optimum gate voltage is 10 to 15V and the output voltage ( $V_{OH}$ ) of type M51995P, FP is about ( $V_{CC}-2V$ ). It is not necessary that the induced voltage is settled higher than the operation start-up voltage  $V_{CC(START)}$ , and the high gate drive voltage causes high gate dissipation, on the other hand, too low gate drive voltage does not make the MOS-FET fully on-state or the saturation state.



**Fig. 25 Start-up circuit diagram when it is necessary to set the start and stop input voltage**

**(2)The start-up circuit when it is necessary to set the start and stop input voltage**

It is recommend to use the third winding of "forward winding" or "positive polarity" as shown in Fig. 25, when the DC source voltages at both the IC operation start and stop must be settled at the specified values.

The input voltage ( $V_{IN(START)}$ ), at which the IC operation starts, is decided by  $R_1$  and  $R_2$  utilizing the low start-up current characteristics of type M51995P, FP.

The input voltage ( $V_{IN(STOP)}$ ), at which the IC operation stops, is decided by the ratio of third winding of transformer.

The  $V_{IN(START)}$  and  $V_{IN(STOP)}$  are given by following equations.

$$V_{IN(START)} \cong R_1 \cdot I_{CCL} + \left( \frac{R_1}{R_2} + 1 \right) \cdot V_{CC(START)} \quad (9)$$

$$V_{IN(STOP)} \cong (V_{CC(STOP)} - V_F) \cdot \frac{N_P}{N_B} + \frac{1}{2} V'_{IN \text{ RIP(P-P)}} \quad (10)$$

where

$I_{CCL}$  is the operation start-up current of IC

$V_{CC(START)}$  is the operation start-up voltage of IC

$V_{CC(STOP)}$  is the operation stop voltage of IC

$V_F$  is the forward voltage of rectifier diode

$V'_{IN \text{ (P-P)}}$  is the peak to peak ripple voltage of

$$V_{CC \text{ terminal}} \cong \frac{N_B}{N_P} V_{IN \text{ RIP(P-P)}}$$

It is required that the  $V_{IN(START)}$  must be higher than  $V_{IN(STOP)}$ .

When the third winding is the "fly back winding" or "reverse

polarity", the  $V_{IN(START)}$  can be fixed, however,  $V_{IN(STOP)}$  can not be settled by this system, so the auxiliary circuit is required.

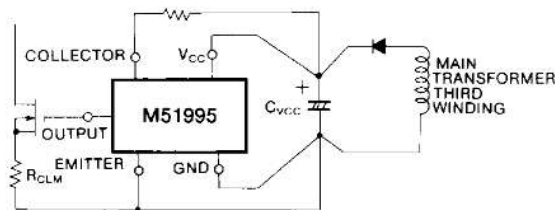
**(3)Notice to the  $V_{CC}$ ,  $V_{CC}$  line and GND line**

To avoid the abnormal IC operation, it is recommended to design the  $V_{CC}$  is not vary abruptly and has few spike voltage, which is induced from the stray capacity between the winding of main transformer.

To reduce the spike voltage, the  $C_{VCC}$ , which is connected between  $V_{CC}$  and ground, must have the good high frequency characteristics.

To design the conductor-pattern on PC board, following cautions must be considered as shown in Fig. 26.

- To separate the emitter line of type M51995 from the the GND line of the IC
- To locate the  $C_{VCC}$  as near as possible to type M51995 and connect directly
- To separate the collector line of type M51995 from the  $V_{CC}$  line of the IC
- To connect the ground terminals of peripheral parts of ICs to GND of type M51995 as short as possible



**Fig. 26 How to design the conductor-pattern of type M51995 on PC board (schematic example)**

**(4)Power supply circuit for easy start-up**

When IC start to operate, the voltage of the  $C_{VCC}$  begins to decrease till the  $C_{VCC}$  becomes to be charged from the third winding of main-transformer as the  $I_{CC}$  of the IC increases abruptly. In case shown in Fig. 24 and 25, some "unstable start-up" or "fail to start-up" may happen, as the charging interval of  $C_{VCC}$  is very short duration; that is the charging does occur only the duration while the induced winding voltage is higher than the  $C_{VCC}$  voltage, if the induced winding voltage is nearly equal to the "operation-stop voltage" of type M51995.

It is recommended to use the 10 to 47 $\mu$ F for  $C_{VCC1}$ , and about 5 times capacity bigger than  $C_{VCC1}$  for  $C_{VCC2}$  in Fig. 27.

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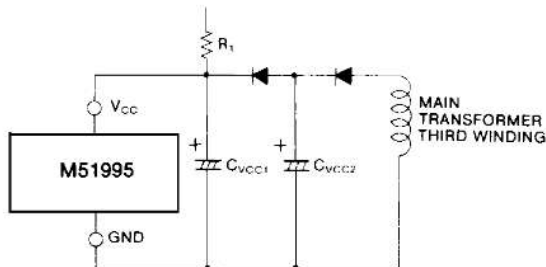


Fig. 27 DC source circuit for stable start-up

**OVP circuit**

**(1) To avoid the miss operation of OVP**

It is recommended to connect the capacitor between OVP terminal and GND for avoiding the miss operation by the spike noise.

The OVP terminal is connected with the sink current source ( $\approx 150\mu A$ ) in IC when OVP does not operate, for absorbing the leak current of the photo coupler in the application.

So the resistance between the OVP terminal and GND for leak-cut is not necessary.

If the resistance is connected, the supply current at the OVP reset supply voltage becomes large.

As the result, the OVP reset supply voltage may become higher than the operation stop voltage.

In that case, the OVP action is reset when the OVP is triggered at the supply voltage a little high than the operation stop voltage.

So it should be avoided absolutely to connect the resistance between the OVP terminal and GND.

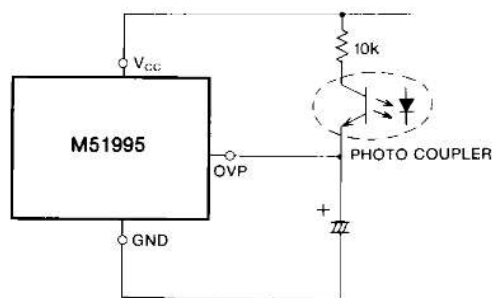


Fig. 28 Peripheral circuit of OVP terminal

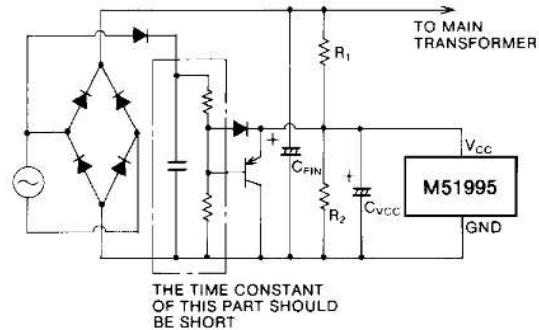


Fig. 29 Example circuit diagram to make the OVP-reset-time fast

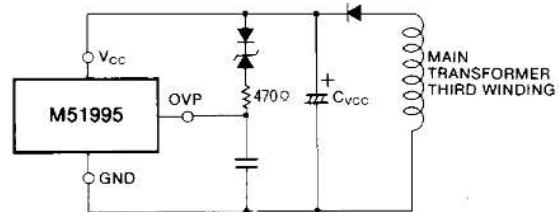


Fig. 30 OVP setting method using the induced third winding voltage on fly back system

**(2) Application circuit to make the OVP-reset time fast**

The reset time may becomes problem when the discharge time constant of  $C_{FIN} \cdot (R_1 + R_2)$  is long. Under such the circuit condition, it is recommended to discharge the  $C_{VCC}$  forcibly and to make the  $V_{CC}$  low value. This makes the OVP-reset time fast.

**(3) OVP setting method using the induced third winding voltage on fly back system**

For the over voltage protection (OVP), the induced fly back type third winding voltage can be utilized, as the induced third winding voltage depends on the output voltage. Fig. 30 shows one of the example circuit diagram.

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**Current limiting circuit**

**(1) Peripheral circuit of CLM+, CLM- terminal**

Fig.31 and 32 show the example circuit diagrams around the CLM+ and CLM- terminal. It is required to connect the low pass filter, in order to reduce the spike current component, as the main current or drain current contains the spike current especially during the turn-on duration of MOS-FET.

1,000pF to 22,000pF is recommended for  $C_{NF}$  and the  $R_{NF1}$  and  $R_{NF2}$  have the functions both to adjust the "current-detecting-sensitivity" and to consist the low pass filter.

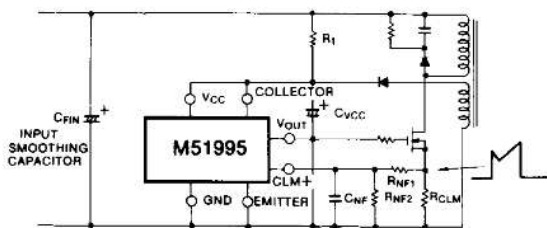


Fig. 31 Peripheral circuit diagram of CLM+ terminal

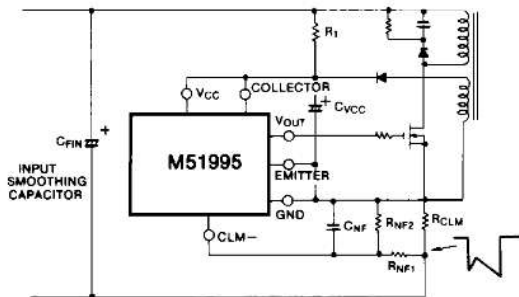


Fig. 32 Peripheral circuit diagram of CLM- terminal

To design the  $R_{NF1}$  and  $R_{NF2}$ , it is required to consider the influence of CLM terminal source current ( $I_{INCLM+}$  or  $I_{INCLM-}$ ), which value is in the range of 90 to 270 $\mu$ A.

In order to be not influenced from these resistor paralleled value of  $R_{NF1}$  and  $R_{NF2}$ , ( $R_{NF1}/R_{NF2}$ ) is recommended to be less than 100 $\Omega$ .

The  $R_{CLM}$  should be the non-inductive resistor.

**(2) Over current limiting curve**

**(a) In case of feed forward system**

Fig. 33 shows the primary and secondary current waveforms under the current limiting operation.

At the typical application of pulse by pulse primary current detecting circuit, the secondary current depends on the primary current. As the peak value of secondary current is limited to specified value, the characteristics curve of output voltage versus output current become to the one as

shown in Fig. 34.

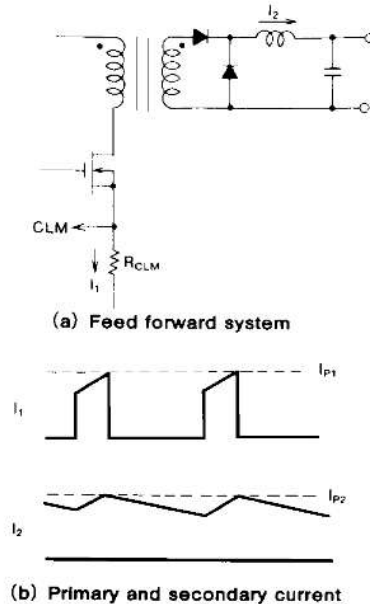


Fig. 33 Primary and secondary current waveforms under the current limiting operation condition on feed forward system

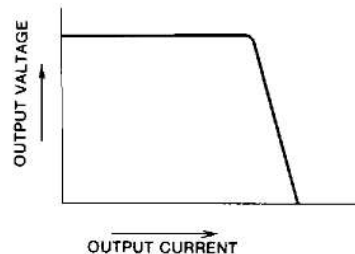


Fig. 34 Over current limiting curve on feed forward system

The demerit of the pulse by pulse current limiting system is that the output pulse width can not reduce to less than some value because of the delay time of low pass filter connected to the CLM terminal and propagation delay time  $T_{PDCLM}$  from CLM terminal to output terminal of type M51995. The typical  $T_{PDCLM}$  is 150ns.

As the frequency becomes higher, the delay time must be shorter. And as the secondary output voltage becomes higher, the dynamic range of on-duty must be wider; it means that it is required to make the on-duration much more narrower. So this system has the demerit at the higher oscillating frequency and higher output voltage applications.

To improve these points, the oscillating frequency is set

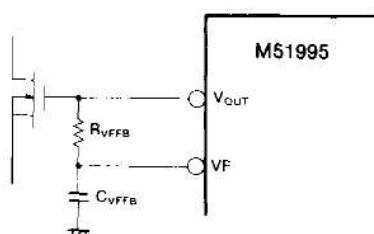
**SWITCHING REGULATOR CONTROL**

low using the characteristics of VF terminal. When the current limiting circuit operates under the over current condition, the oscillating frequency decreases in accordance with the decrease of VF terminal voltage, if the VF is lower than 3.5V. And also the dead time becomes longer.

Under the condition of current limiting operation, the output current  $I_2$  continues as shown in Fig. 33. So the output voltage depends on the product of the input primary voltage  $V_{IN}$  and the on-duty.

If the third winding polarity is positive, the  $V_{CC}$  depends on  $V_{IN}$ , so it is concluded that the smoothed voltage of  $V_{OUT}$  terminal depends on the output DC voltage of the SMPS.

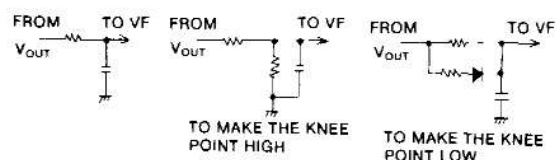
So the sharp current limiting characteristics will be got, if the  $V_{OUT}$  voltage is feed back to VF terminal through low pass filter as shown in Fig. 35.



**Fig. 35** Feed back loop through low pass filter from  $V_{OUT}$  to VF terminal

It is recommended to use  $15k\Omega$  for  $R_{VFFB}$ , and  $10,000pF$  for  $C_{VFFB}$  in Fig.35.

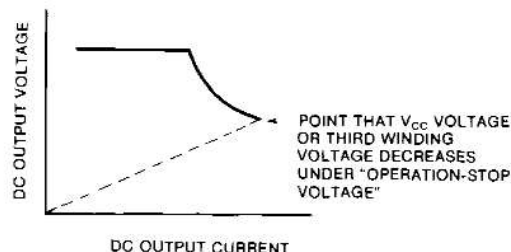
Fig. 36 shows how to control the knee point where the frequency becomes decrease.



**Fig. 36** How to control the knee point

**(b)In case of fly back system**

The DC output voltage of SMPS depends on the  $V_{CC}$  voltage of type M51995 when the polarity of the third winding is negative and the system is fly back. So the operation of type M51995 will stop when the  $V_{CC}$  becomes lower than "Operation-stop voltage" of M51995 when the DC output voltage of SMPS decreases under specified value at over load condition.



**Fig. 37** Over current limiting curve on fly back system

However, the M51995 will non-operate and operate intermittently, as the  $V_{CC}$  voltage rises in accordance with the decrease of  $I_{CC}$  current.

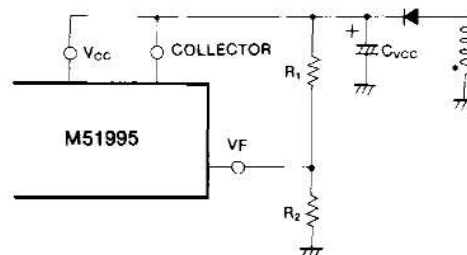
The fly back system has the constant output power characteristics as shown in Fig. 37 when the peak primary current and the operating frequency are constant.

To control the increase of DC output current, the operating frequency is decreased using the characteristics of VF terminal when the over current limiting function begins to operate.

The voltage which made by dividing the  $V_{CC}$  is applied to VF terminal as shown in Fig.38, as the induced third winding voltage depends on the DC output voltage of SMPS.

$15k\Omega$  or less is recommended for  $R_2$  in Fig. 38, it is noticed that the current flows through  $R_1$  and  $R_2$  will superpose on the  $I_{CC(START)}$  current.

If the  $R_1$  is connected to  $C_{VCC2}$  in Fig. 27, the current flows through  $R_1$  and  $R_2$  is independent of the  $I_{CC(START)}$ .



**Fig. 38** Circuit diagram to make knee point low on fly back system

**(c)Application circuit to keep the non-operating condition when over load current condition will continue for specified duration**

The CT terminal voltage will begin to rise and the capacitor connected to CT terminal will be charged-up, if the current limiting function starts and VF terminal voltage decreases below  $V_{THIME}(\approx 3V)$ .

If the charged-up CT terminal voltage is applied to OVP terminal through the level-shifter consisted of buffer transistor and resistor, it makes type M51995 keep non-operating condition.



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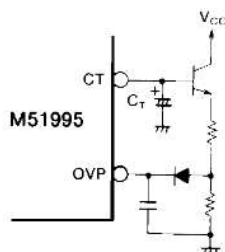


Fig. 39 Application circuit diagram to keep the non-operating condition when over load current condition will continue for specified duration

### Output circuit

(1) The output terminal characteristics at the  $V_{CC}$  voltage lower than the "Operation-stop" voltage

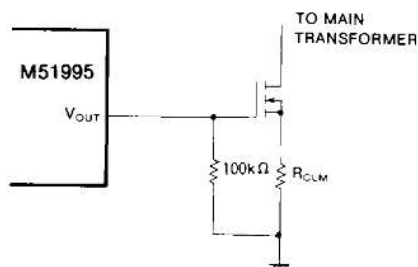


Fig. 40 Circuit diagram to prevent the MOS-FET gate potential rising

The output terminal has the current sink ability even though the  $V_{CC}$  voltage lower than the "Operation-stop" voltage or  $V_{CC(STOP)}$ . (It means that the terminal is "Output low state" and please refer characteristics of output low voltage versus sink current.)

This characteristics has the merit not to damage the MOS-FET at the stop of operation when the  $V_{CC}$  voltage decreases lower than the voltage of  $V_{CC(STOP)}$ , as the gate charge of MOS-FET, which shows the capacitive load characteristics to the output terminal, is drawn out rapidly.

The output terminal has the draw-out ability above the  $V_{CC}$  voltage of 2V, however, lower than the 2V, it loses the ability and the output terminal potential may rise due to the leakage current.

In this case, it is recommended to connect the resistor of 100kΩ between gate and source of MOS-FET as shown in Fig. 40.

### (2) MOS-FET gate drive power dissipation

Fig. 41 shows the relation between the applied gate voltage and the stored gate charge.

In the region ①, the charge is mainly stored at  $C_{GS}$  as the depletion is spread and  $C_{GD}$  is small owing to the off-state of MOS-FET and the high drain voltage.

In the region ②, the  $C_{GD}$  is multiplied by the "mirror effect"

as the characteristics of MOS-FET transfers from off-state to on-state.

In the region ③, both the  $C_{GD}$  and  $C_{GS}$  affect to the characteristics as the MOS-FET is on-state and the drain voltage is low.

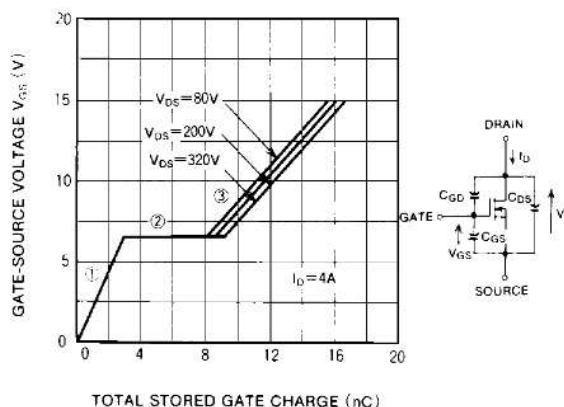


Fig. 41 The relation between applied gate-source voltage and stored gate charge

The charging and discharging current caused by this gate charge makes the gate power dissipation. The relation between gate drive current  $I_D$  and total gate charge  $Q_{GSH}$  is shown by following equation:

$$I_D = Q_{GSH} \cdot f_{OSC} \quad \text{.....(1)}$$

Where

$f_{OSC}$  is switching frequency

As the gate drive current may reach up to several tenths milliampere at 500kHz operation, depending on the size of MOS-FET, the power dissipation caused by the gate current can not be neglected.

In this case, following action will be considered to avoid heat up of type M51995.

- (1) To attach the heatsink to type M51995
- (2) To use the printed circuit board with the good thermal conductivity
- (3) To use the buffer circuit shown next section

### (3) Output buffer circuit

It is recommended to use the output buffer circuit as shown in Fig. 42, when type M51995 drives the large capacitive load or bipolar transistor.



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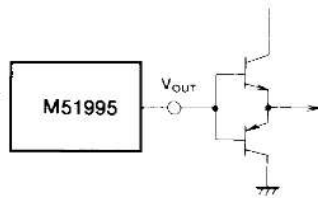


Fig. 42 Output buffer circuit diagram

**DET**

Fig. 43 shows how to use the DET circuit for the voltage detector and error amplifier.

For the phase shift compensation, it is recommended to connected the CR network between DET terminal and F/B terminal.

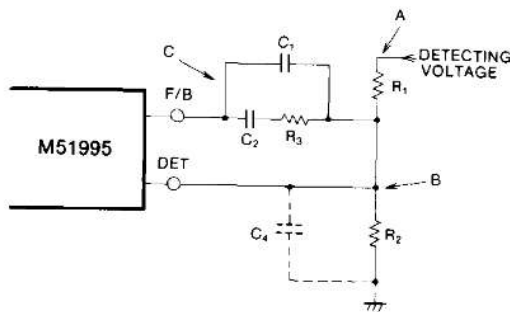


Fig. 43 How to use the DET circuit for the voltage detector

Fig. 44 shows the gain-frequency characteristics between point B and point C shown in Fig. 43.

The  $G_1$ ,  $\omega_1$  and  $\omega_2$  are given by following equations;

$$G_1 = \frac{R_3}{R_1 // R_2} \quad (11)$$

$$\omega_1 = \frac{1}{C_2 \cdot R_3} \quad (12)$$

$$\omega_2 = \frac{C_1 + C_2}{C_1 \cdot C_2 \cdot R_3} \quad (13)$$

At the start of the operation, there happen to be no output pulse due to F/B terminal current through  $C_1$  and  $C_2$ , as the potential of F/B terminal rises sharply just after the start of the operation.

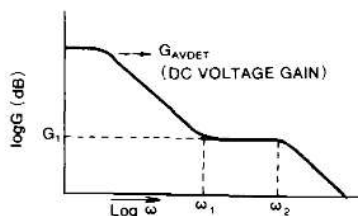


Fig. 44 Gain-frequency characteristics between point B and C shown in Fig. 43

Not to lack the output pulse, is recommended to connect the capacitor  $C_4$  as shown by broken line.

Please take notice that the current flows through the  $R_1$  and  $R_2$  are superposed to  $I_{CC(START)}$ . Not to superpose,  $R_1$  is connected to  $C_{VCC2}$  as shown in Fig. 27

**How to get the narrow pulse width during the start of operation**

Fig. 45 shows how to get the narrow pulse width during the start of the operation. If the pulse train of forcibly narrowed pulse-width continues too long, the misstart of operation may happen, so it is recommended to make the output pulse width narrow only for a few pulse at the start of operation.  $0.1 \mu F$  is recommended for the C.

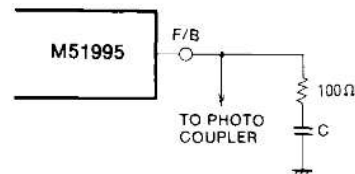


Fig. 45 How to get the narrow pulse width during the start of operation

**How to synchronize with external circuit**

Type M51995 has no function to synchronize with external circuit, however, there is some application circuit for synchronization as shown in Fig. 46. If this circuit is used, the synchronization may be out of order at the overload condition when the current limiting function starts to operate and VF terminal voltage becomes lower than 3V.

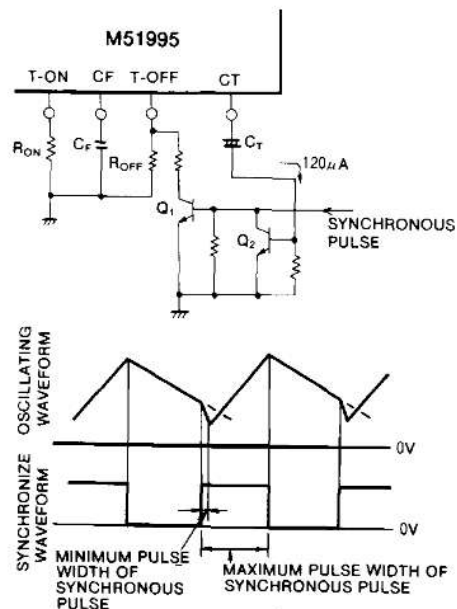


Fig. 46 How to synchronize with external circuit

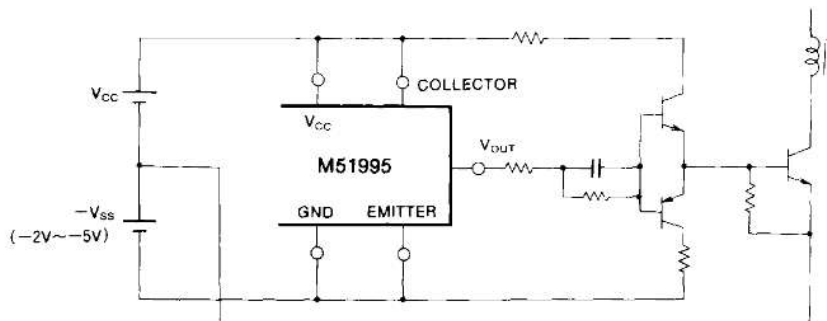
**SWITCHING REGULATOR CONTROL**

Fig. 47 Driver circuit diagram (1) for bipolar transistor

**Driver circuit for bipolar transistor**

When the bipolar transistor is used instead of MOS-FET, the base current of bipolar transistor must be sunk by the negative base voltage source for the switching-off duration, in order to make the switching speed of bipolar transistor fast one.

In this case, over current can not be detected by detecting resistor in series to bipolar transistor, so it is recommended to use the CT(current transformer).

For the low current rating transistor, type M51995 can drive it directly as shown in Fig. 48.

**Attention for heat generation**

The maximum ambient temperature of type M51995 is  $+85^{\circ}\text{C}$ , however, the ambient temperature in vicinity of the IC is not uniform and varies place by place, as the amount of power dissipation is fairly large and the power dissipation is generated locally in the switching regulator.

So it is one of the good idea to check the IC package temperature. The temperature difference between IC junction and the surface of IC package is  $15^{\circ}\text{C}$  or less, when the IC junction temperature is measured by temperature dependency of forward voltage of pn junction, and IC package temperature is measured by "thermo-viewer", and also the IC is mounted on the "phenol-base" PC board in normal atmosphere.

So it is concluded that the maximum case temperature (surface temperature of IC) rating is  $120^{\circ}\text{C}$  with adequate margin.

As type M51995 has the modified totempole driver circuit, the transient through current is very small and the total power dissipation is decreased to the reasonable power level.

Fig. 49 shows the transient rush (through) current waveforms at the rising and falling edges of output pulse, respectively.

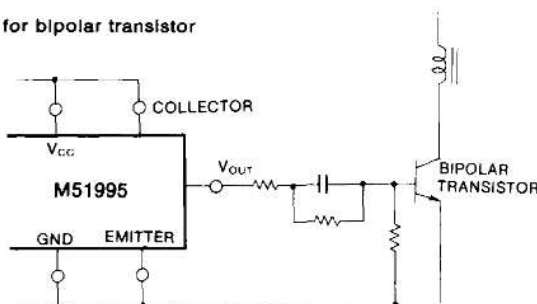
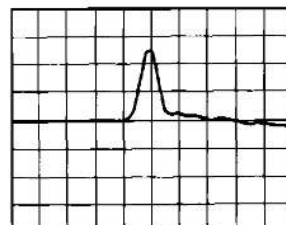
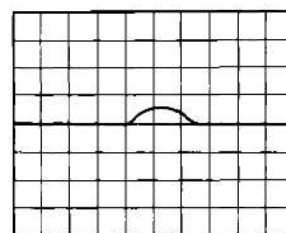


Fig. 48 Driver circuit diagram (2) for small bipolar transistor



H-Axis : 20ns/div  
V-Axis : 50mA/div  
AT RISING EDGE OF  
OUTPUT PULSE



H-Axis : 20ns/div  
V-Axis : 10mA/div  
AT FALLING EDGE OF  
OUTPUT PULSE

Fig. 49 Through current waveforms of totempole driver circuit at no-load and  $V_{CC}$  of 18V condition

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**APPLICATION EXAMPLE**

Feed forward types SMPS with multi-output.

